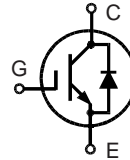


High Voltage BIMOSFET™ Monolithic Bipolar MOS Transistor

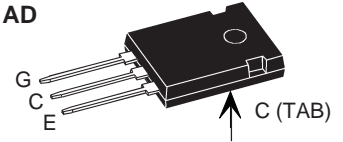
IXBH 9N140G
IXBH 9N160G

$V_{CES} = 1400/1600\text{ V}$
 $I_{C25} = 9\text{ A}$
 $V_{CE(sat)} = 4.9\text{ V typ.}$
 $t_{fi} = 70\text{ ns}$

N-Channel, Enhancement Mode
MOSFET compatible



TO-247 AD



G = Gate, C = Collector,
E = Emitter, TAB = Collector

Preliminary Data

Symbol	Conditions	Maximum Ratings		
		9N140G	9N160G	
V_{CES}	$T_J = 25^\circ\text{C to } 150^\circ\text{C}$	1400	1600	V
V_{CGR}	$T_J = 25^\circ\text{C to } 150^\circ\text{C}; R_{GE} = 1\text{ M}\Omega$	1400	1600	V
V_{GES}	Continuous		± 20	V
V_{GEM}	Transient		± 30	V
I_{C25}	$T_C = 25^\circ\text{C}$,		9	A
I_{C90}	$T_C = 90^\circ\text{C}$		5	A
I_{CM}	$T_C = 25^\circ\text{C}$, 1 ms		10	A
SSOA (RBSOA)	$V_{GE} = 10\text{ V}$, $T_{VJ} = 125^\circ\text{C}$, $R_G = 27\ \Omega$, $V_{CE} = 0.8 \cdot V_{CES}$, Clamped inductive load, $L = 100\ \mu\text{H}$		$I_{CM} = 12$	A
P_C	$T_C = 25^\circ\text{C}$		100	W
T_J		-55 ... +150		$^\circ\text{C}$
T_{JM}			150	$^\circ\text{C}$
T_{stg}		-55 ... +150		$^\circ\text{C}$
T_L	1.6 mm (0.063 in) from case for 10 s		300	$^\circ\text{C}$
M_d	Mounting torque		1.15/10	Nm/lb.in.
Weight			6	g

Features

- High Voltage BIMOSFET™
 - replaces high voltage Darlington's and series connected MOSFET's
 - lower effective $R_{DS(on)}$
- MOS Gate turn-on
 - drive simplicity
 - MOSFET compatible for 10V turn on gate voltage
- Monolithic construction
 - high blocking voltage capability
 - very fast turn-off characteristics
- International standard package JEDEC TO-247 AD
- Reverse conducting capability

Applications

- Flyback converters
- DC choppers
- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies
- CRT deflection
- Lamp ballasts

Advantages

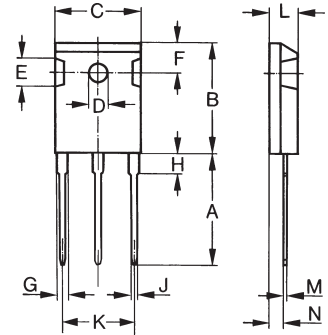
- Easy to mount with 1 screw (isolated mounting screw hole)
- Space savings
- High power density

Symbol	Conditions	Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified)		
		min.	typ.	max.
BV_{CES}	$I_C = 0.25\text{ mA}$, $V_{GE} = 0\text{ V}$	9N140G 9N160G	1400 1600	V
$V_{GE(th)}$	$I_C = 0.5\text{ mA}$, $V_{CE} = V_{GE}$		3.5	5.5 V
I_{CES}	$V_{CE} = 0.8 \cdot V_{CES}$, $V_{GE} = 0\text{ V}$	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$		0.1 100 μA mA
I_{GES}	$V_{CE} = 0\text{ V}$, $V_{GE} = \pm 20\text{ V}$			$\pm 500\text{ nA}$
$V_{CE(sat)}$	$I_C = I_{C90}$, $V_{GE} = 15\text{ V}$	$T_J = 125^\circ\text{C}$	4.9 5.6	7 V V

Symbol	Conditions	Characteristic Values		
		(T _J = 25°C, unless otherwise specified)		
		min.	typ.	max.
C _{ies}	} V _{CE} = 25 V, V _{GE} = 0 V, f = 1 MHz		550	pF
C _{oes}			36	pF
C _{res}			5	pF
Q _g	I _C = 5 A, V _{CE} = 600 V, V _{GE} = 10 V		34	nC
t _{d(on)}	} Inductive load, T_J = 125°C I _C = I _{C90} , V _{GE} = 10 V, L = 100 μH, V _{CE} = 960 V, R _G = 27 Ω		140	ns
t _{ri}			200	ns
t _{d(off)}			120	ns
t _{fi}			70	ns
R _{thJC}				1.25 K/W
R _{thCK}		0.25		K/W

Reverse Conduction **Characteristic Values**
(T_J = 25°C, unless otherwise specified)

Symbol	Conditions	min.	typ.	max.
V _F	I _F = I _{C90} , V _{GE} = 0 V		3.6	5

TO-247 AD Outline


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G	1.65	2.13	0.065	0.084
H	-	4.5	-	0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	1.5	2.49	0.087	0.102

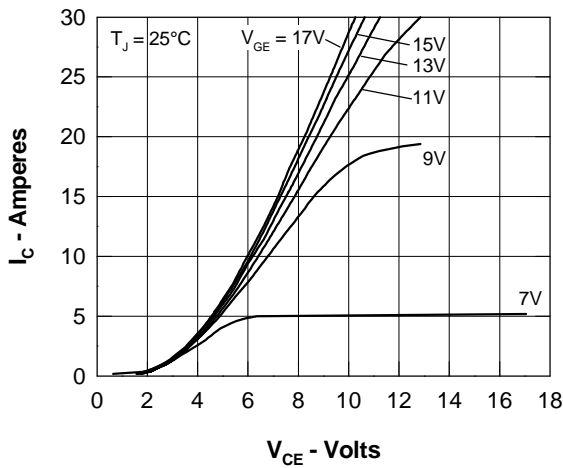


Fig. 1 Typ. Output Characteristics

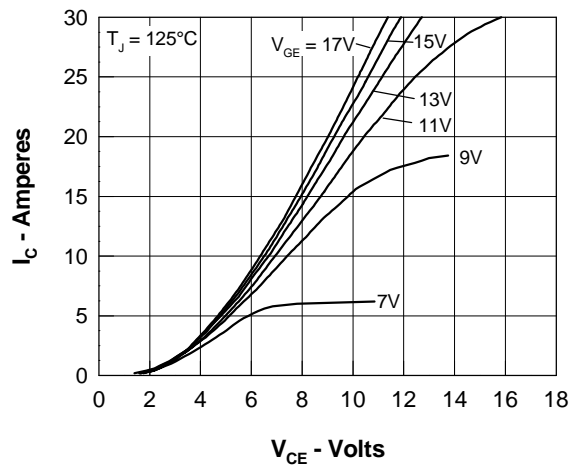


Fig. 2 Typ. Output Characteristics

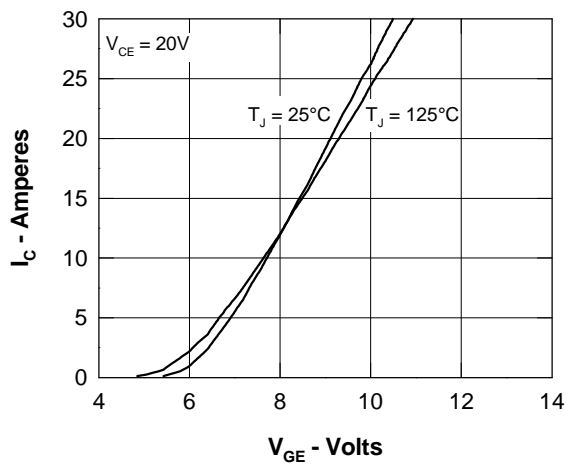


Fig. 3 Typ. Transfer Characteristics

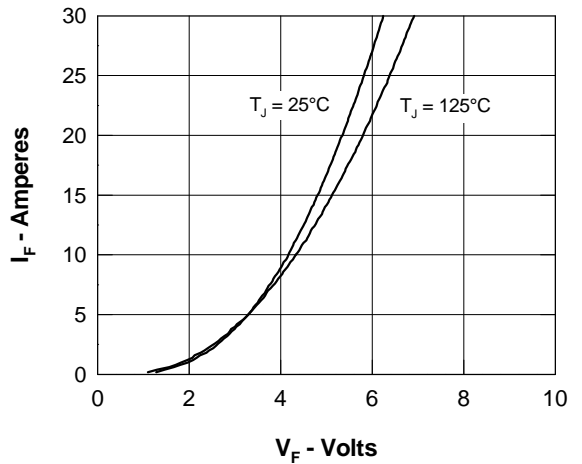


Fig. 4 Typ. Characteristics of Reverse Conduction

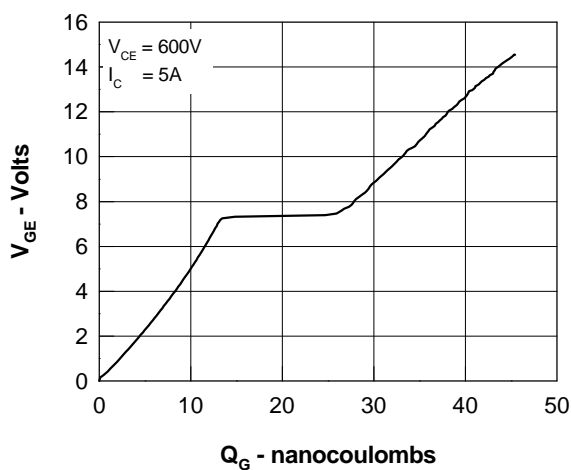


Fig. 5 Typ. Gate Charge characteristics

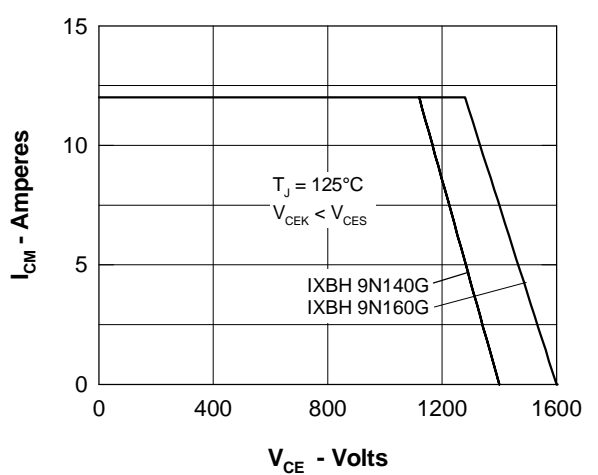


Fig. 6 Reverse Biased Safe Operating Area RBSOA

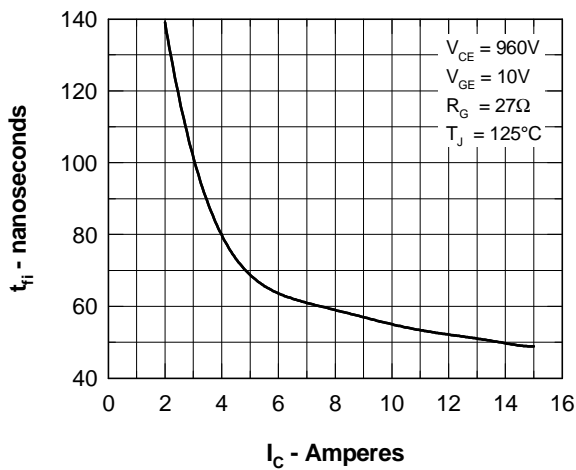


Fig. 7 Typ. Fall Time

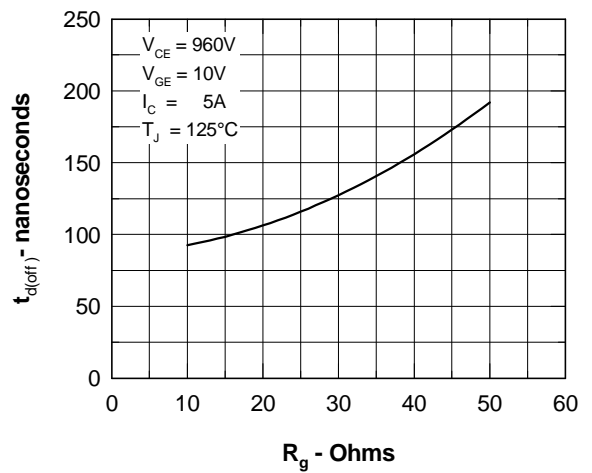


Fig. 8 Typ. Turn Off Delay Time

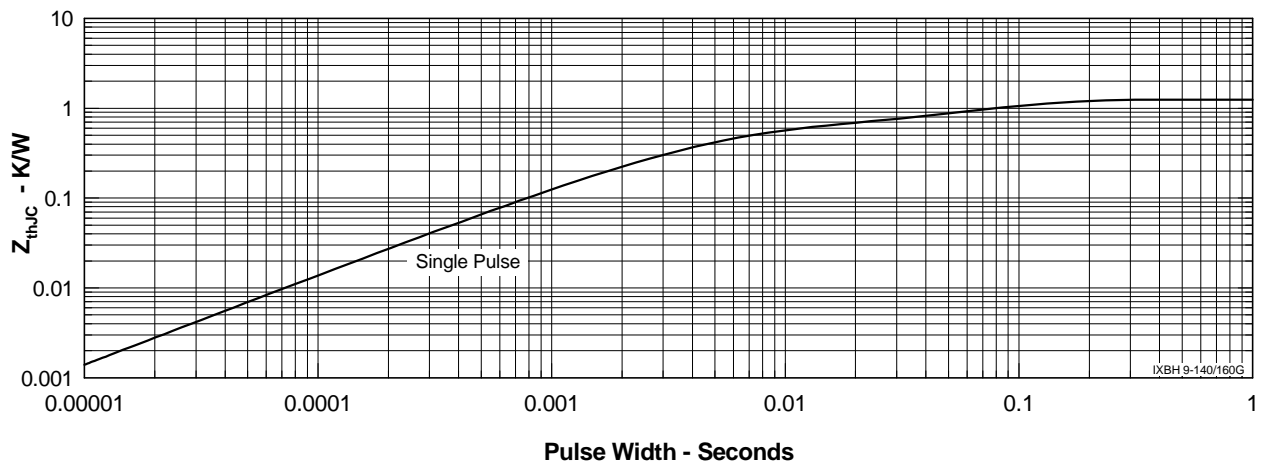


Fig. 9 Typ. Transient Thermal Impedance



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